

## Innovative technologies, devices and materials



ECTS  
5 crédits



Hourly volume  
54h

### Introducing

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#### Objectives

At the end of this module, the student will have understood and be able to explain:

- plasma processes
- new technologies and materials for the microelectronics applications
- concepts of the physics of continuous media
- quantum phenomena such as diffusion, electron paramagnetic resonance, and quantum cryptography: entangled states, single-photon and pairs of entangled states source based on semiconductors quantum dots.

The student will be able to apply the quantum mechanics formalism to describe innovative devices at the nano-scale.

The student will be able to:

- choose the kind of scanning probe microscopy well adapted to a specific application/characterization
- analyze and interpret basic images of scanning probe microscopy.

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### Necessary prerequisites

Electromagnetism

Quantum Mechanics (I4GPPM11)

Mathematics: matrix calculus and differential equations

Physical Metallurgy (real crystal, diffusion, precipitation, nucleation and growth)

Basic knowledge of symbolic computational tool like Maxima.

### Practical info

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#### Location(s)

 Toulouse